## **DECLARATION AND POWER OF ATTORNEY**

As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name;

I believe I am the original, first, and sole inventor (if only one name is listed below) or an original, first, and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

## SEMICONDUCTOR LIGHT EMITTING DEVICE AND METHOD FOR MANUFACTURING THE SAME

	s Application	hich (check one) <u>X</u> n Serial No					(if
		nave reviewed and as amended by any				entified spec	ification,
		ity to disclose inform tle 37, Code of Fed				on of this ap	plication
application	n(s) for pate n for patent	n priority benefits unent or inventor's certific or inventor's certific	tificate listed be	low and have a	also identific	ed below any	y foreign
Prior Foreign Application(s)					Priority Yes	Claimed No	
Number	Country	Day/Month/Year	Filed	_			
Number	Country	Day/Month/Year	Filed	<b></b> -	<del></del>		
Number	Country	Day/Month/Year	Filed	_		<del></del>	
agent(s) to connected  Michael A	o prosecute therewith: GLENN, I	NEY: As a named this application are	nd transact all	ereby appoint to business in the DRICKS, Reg. 1	Patent an	d Trademar	k Office
		ist pher PEIL, Reg	j. No. 45,005; a	ind Julia THOM	<b>⁄lAS</b> , Reg. I	No. 52,283	

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I hereby claim the benefit under Title 35, United States code, Section 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, Section 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, Section 1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:								
Application Ser. No. Filing Date Status: Patented, Pending, Abandoned								
######################################								
I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.								
Full name of sole or first inventor:Tzong-Liang TSAI								
Inventor's signature Dorg Law June 19, 2003  Date								
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Inventor's signature Chin-Sung Chang June 19, 2003								
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